## NSN 5961-00-123-5764

Transistor - Page 1 of 1

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-123-5764 **Inclosure Material:** Metal **Overall Length:** 0.325 inches **Overall Diameter:** 0.830 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-emitter, base open and 110.0 collector to emitter voltage, dc with base short-circuited to emitter and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 117.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No